Unit in mm

TOSHIBA TRANSISTOR SILICON PNP TRIPLE DIFFUSED TYPE

2 S A 1 9 7 1

HIGH VOLTAGE SWITCHING APPLICATIONS

• High Voltage : $V_{CE} = -400 \, V$

MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC			SYMBOL	RATING	UNIT	
Collector-Base Voltage			v_{CBO}	-400	V	
Collector-Emitter Voltage			V_{CEO}	-400	V	
Emitter-Base Voltage			$V_{ m EBO}$	-7	V	
Collector Current		DC	$I_{\mathbf{C}}$	-0.5	A	
		Pulse	I_{CP}	-1		
Base Current			$I_{\mathbf{B}}$	-0.25	A	
Collector Power T	Га =	25°C	$P_{\mathbf{C}}$	500	mW	
Dissipation	Га =	25°C (Note)	10	1000		
Junction Temperature			Tj	150	°C	
Storage Temperature Range			$\mathrm{T_{stg}}$	-55~150	$^{\circ}\mathrm{C}$	

(Note) : Mounted on Ceramic Substrate (250 $mm^2\times 0.8\,t)$

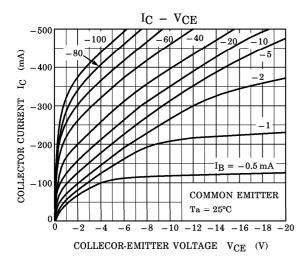
I -	DMAX. 0.4± NAM. 0.4± NAM. 0.40 NAM. 0.40 NAM. 0.40 NAM. 0.80 NAM. 0.40 NAM. 0.80 NAM. 0.40 NAM. 0.40	0.05
JEDEC	_	
JEITA	_	
TOSHIBA	2-5KIA	

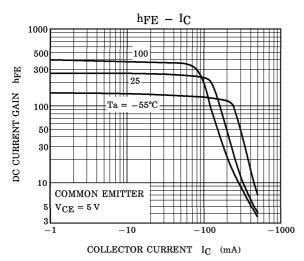
Weight: 0.05 g (Typ.)

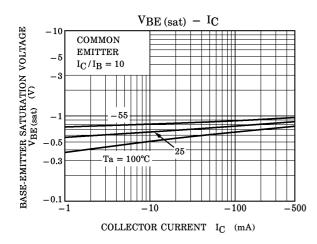
ELECTRICAL CHARACTERISTICS (Ta = 25°C)

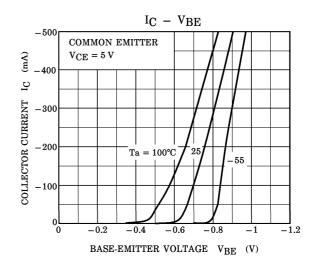
CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current		ICBO	$V_{CB} = -400 \text{ V}, I_{E} = 0$	_	_	-10	μ A
Emitter Cut-off Current		I_{EBO}	$V_{EB} = -7 \text{ V}, I_{C} = 0$	_	_	-1	μ A
Collector-Emitter Breakdown Voltage		V (BR) CEO	$_{ m CEO}$ $I_{ m C}=-10$ mA, $I_{ m B}=0$		_	_	V
DC Current Gain		h _{FE} (1)	$V_{CE} = -5 \text{ V}, I_{C} = -20 \text{ mA}$	140	_	450	
		h _{FE} (2)	$V_{CE} = -5 V, I_{C} = -100 mA$	140	_	400	
Collector-Emitter Saturation Voltage		V _{CE} (sat)	$I_{\rm C} = -100{\rm mA},\ I_{\rm B} = -10{\rm mA}$	1	-0.4	-1.0	V
Base-Emitter Saturation Voltage		V _{BE} (sat)	$I_{\rm C} = -100{\rm mA},\ I_{\rm B} = -10{\rm mA}$	_	-0.76	-0.9	V
Transition Frequency		$ m f_{T}$	$V_{CE} = -5 \text{ V}, I_{C} = -50 \text{ mA}$	_	35	_	MHz
Collector Output Capacitance		C_{ob}	$V_{CB} = -10 \text{ V}, I_{E} = 0, f = 1 \text{ MHz}$	_	18	_	рF
Switching Time	Turn-on Time	ton	20 μs OUTPUT IB1 IB2 IB2 IB2	1	0.2	_	
	Storage Time	$t_{ m stg}$	I_{B1} I_{B2} I_{B2} I_{B2} $V_{CC} = -200 \text{ V}$	_	2.3	_	μs
	Fall Time	t _f	$I_{B1} = -10 \text{ mA}, \ I_{B2} = 20 \text{ mA}$ $DUTY \ CYCLE \le 1\%$	_	0.2	_	

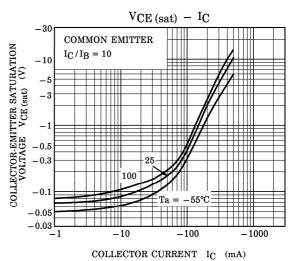
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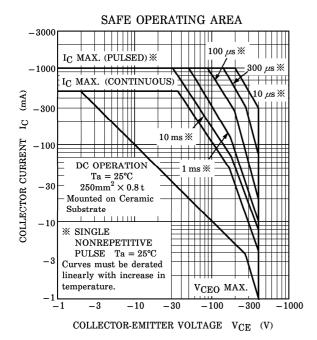








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